# imall

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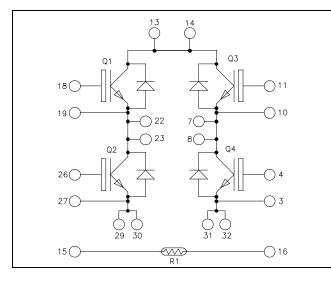
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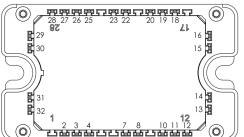




Power Matters."

Full bridge High speed Trench + Field Stop IGBT4 Power Module





All multiple inputs and outputs must be shorted together Example: 13/14 ; 29/30 ; 22/23 ...

### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

### Absolute maximum ratings (per IGBT)

Symbol	Parameter		Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Voltage		650	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	135	
I <sub>C</sub>	$T_{\rm C} = 60^{\circ}{\rm C}$		100	Α
I <sub>CM</sub>	Pulsed Collector Current	$T_C = 25^{\circ}C$	270	
$V_{GE}$	Gate – Emitter Voltage		$\pm 20$	V
PD	Power Dissipation		350	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

### $V_{CES} = 650V$ $I_{C} = 100A$ @ Tc = 60°C

### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### Features

- High speed Trench + Field Stop IGBT 4
  - Low voltage drop
  - Low leakage current
  - Low switching losses
  - Very low stray inductance
- Internal thermistor for temperature monitoring

#### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS compliant

1 - 6



### Power Matters."

### Electrical Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$				50	μΑ
V	Collector Emitter Saturation Voltage	, GE 10 ,	$T_j = 25^{\circ}C$	1.4	1.85	2.3	V
V <sub>CE(sat)</sub>			$T_{j} = 150^{\circ}C$		2.2		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 1.6 \text{ mA}$		4.2	5.1	5.6	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				150	nA

### Dynamic Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		6100		
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 25V$		232		pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz		180		
Q <sub>G</sub>	Gate charge	$V_{GE} = 15V, I_C = 100A$ $V_{CE} = 480V$		630		nC
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (25°C)		19		
T <sub>r</sub>	Rise Time	$V_{GE} = \pm 15V$		33		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 400V$ $I_{C} = 100A$		197		ns
T <sub>f</sub>	Fall Time	$R_G = 3.6\Omega$		21		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (150°C	)	19		
T <sub>r</sub>	Rise Time	$V_{GE} = \pm 15V$		29		ns
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 400V$ $I_{C} = 100A$		227		
$T_{f}$	Fall Time	$R_G = 3.6\Omega$		22		
Eon	Turn on Energy	$\begin{array}{c} V_{GE} = \pm 15V \\ V_{Bus} = 400V \end{array} \qquad T_j = 150^{\circ}C \end{array}$		2.4		mI
$\mathrm{E}_{\mathrm{off}}$	Turn off Energy	$\begin{array}{c} I_{C} = 100 A \\ R_{G} = 3.6 \Omega \end{array} \qquad T_{j} = 150^{\circ} C \end{array}$		2		mJ
R <sub>G</sub>	Integrated gate resistor			2		Ω
I <sub>sc</sub>	Short Circuit data	$\begin{array}{l} V_{GE}\!\leq\!\!15V\ ;  V_{Bus}\!=\!400V \\ t_p\!\leq\!\!5\mu s\ ;  T_j\!=\!150^\circ\!C \end{array}$		700		А
R <sub>thJC</sub>	Junction to Case Thermal Resistance	;			0.44	°C/W

### Diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage					650	V
I <sub>RM</sub>	Reverse Leakage Current	$V_R = 650V$				50	μA
$I_F$	DC Forward Current		$Tc = 25^{\circ}C$		100		Α
$V_{\rm F}$	Diode Forward Voltage	$I_{\rm F} = 100 \text{A}$ $V_{\rm GE} = 0 \text{V}$	$T_i = 25^{\circ}C$ $T_i = 150^{\circ}C$		1.6 1.5	2	V
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25^{\circ}C$ $T_i = 150^{\circ}C$		125 220		ns
Q <sub>rr</sub>	Reverse Recovery Charge	$I_{\rm F} = 100 \text{A}$ $V_{\rm R} = 300 \text{V}$ $di/dt = 2000 \text{A}/\mu \text{s}$	$T_j = 25^{\circ}C$ $T_i = 150^{\circ}C$		4.7 9.9		μC
E <sub>rr</sub>	Reverse Recovery Energy	a. a. 200010 µ5	$T_j = 25^{\circ}C$ $T_i = 150^{\circ}C$		1.1 2.4		mJ
R <sub>thJC</sub>	Junction to Case Thermal Resistance	-	• *			0.77	°C/W

APTGLQ100H65T3G-Rev 0 August, 2016

www.microsemi.com

2 - 6



Power Matters."

### Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

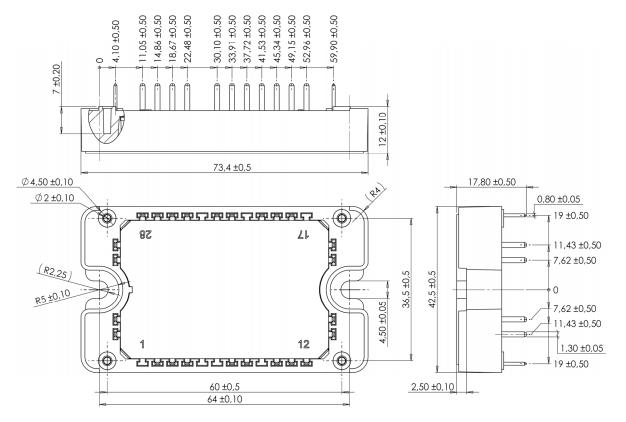
Symbol	Characteristic	11	,	Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C				50		kΩ
$\Delta R_{25}/R_{25}$					5		%
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$				3952		Κ
$\Delta B/B$			T <sub>C</sub> =100°C		4		%
		D					

 $R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$  T: Thermistor temperature R<sub>T</sub>: Thermistor value at T

### Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case	4000		V		
T <sub>J</sub>	Operating junction temperature range			-40	175	
T <sub>JOP</sub>	Recommended junction temperature under sy	witching condit	ions	-40	T <sub>J</sub> max -25	°C
T <sub>STG</sub>	Storage Temperature Range			-40	125	C
T <sub>C</sub>	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

### Package outline (dimensions in mm)



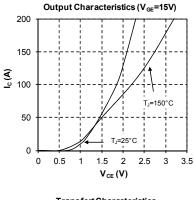
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

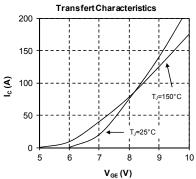
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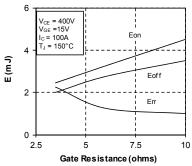
#### Power Matters."

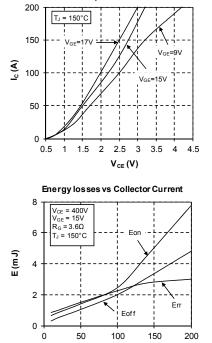
### Typical performance curve





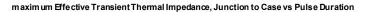
Switching EnergyLosses vs Gate Resistance

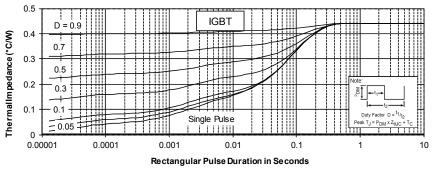




I<sub>c</sub> (A)

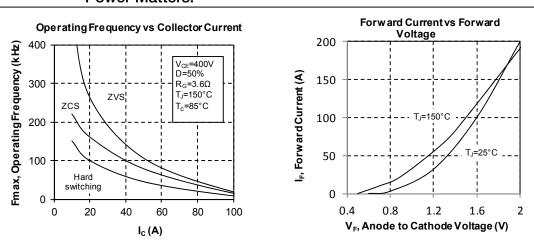
**Output Characteristics** 



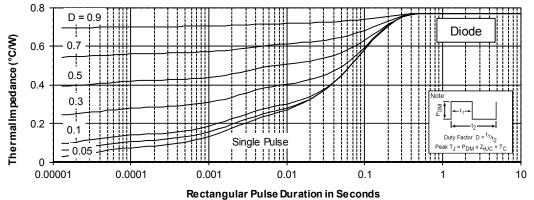


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